In Situ Fabrication of Lead-Free Double Perovskite/Polymer Composite Films for Optoelectronic Devices and Anticounterfeit Printing

Jindou Shi, Minqiang Wang,* Chen Zhang, Junnan Wang, Yun Zhou, Youlong Xu, Nikolai V. Gaponenko, and Arshad Saleem Bhatti



bright orange luminescence with a photoluminescence quantum yield (PLQY) of up to 21.52%. Moreover, the growth dynamics of $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PMMA$ CFs was further investigated by in situ optical transformation, which was extended to other DP-based polymer CFs. Finally, these CFs exhibited excellent performance in optoelectronic devices and anticounterfeit printing, the results of which provide a new pathway to advance the development of lead-free DP materials in the optical field.

KEYWORDS: Lead-free double perovskites, Dimethyl sulfoxide, Composite films, Cs₂Na_{1-x}Ag_xBiCl₆/PMMA, Optoelectronic devices

INTRODUCTION

In the past several years, lead halide perovskite $APbX_3$ (A = $CH_3NH_3^+$, Cs^+ ; X = Cl⁻, Br⁻, I⁻) nanocrystals (NCs) have been considered the most promising material for the next generation of optoelectronic devices benefiting from their excellent optical and electronic properties.¹⁻⁵ Unfortunately, the inherent toxicity of Pb2+ does not meet current requirements for environmentally friendly materials and seriously limits its application in commercial devices, so the replacement of Pb²⁺ with less toxic or nontoxic elements has become an effective solution and acquired widespread attention.⁶⁻⁸ Typically, the divalent metal cations employed in the isovalent substitution are very unstable and highly susceptible to oxidation,^{9,10} so the combination of monovalent (B^+) and trivalent (B^{3+}) metal cations was adopted to heterovalently substitute Pb²⁺ for synthesis of lead-free double perovskite (DP) as one of the most reliable strategies.¹¹⁻¹⁴ Currently, the method of obtaining most DPs was by introducing concentrated hydrochloric acid (HCl) as a solvent and growing them at high temperatures for long periods of time.¹⁵ Such a preparation strategy not only adds to the experimental risk and cost but also pollutes the environment

with concentrated HCl,¹⁶ so it is urgent to have a convenient and low-consumption preparation strategy to accomplish the heterovalent substitution of Pb^{2+} .

Nowadays, numerous researchers have synthesized DP materials with a variety of excellent optical properties at different scales utilizing heterovalent substitution, completely overcoming the toxicity of Pb^{2+} .^{17–19} The 20% Mn^{2+} -doped $Cs_2Na_{0.2}Ag_{0.8}InCl_6$ DP single crystal (SC) with a maximum emission peak located at 620 nm corresponding to a photoluminescence quantum yield (PLQY) of 32% was acquired by slow crystallization at 180 °C for 50 h through the hydrothermal method in concentrated HCl as a solvent.²⁰ Besides, $Cs_2AgInCl_6$:Bi NCs with good monodispersity were obtained by rapid injection of cesium oleate solutions into precursors containing HCl at 280 °C employing a fabrication

Received:December 19, 2022Accepted:February 14, 2023Published:February 23, 2023





www.acsami.org



Figure 1. (a) XRD patterns of $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs with different Ag^+ content (the bottom corresponds to a pure bulk $Cs_2NaBiCl_6$ (ICSD: 2738) and the top to a pure bulk $Cs_2AgBiCl_6$ (ICSD: 291598). SEM images of (b) pure PMMA film, (c) $Cs_2NaBiCl_6/PMMA$ CFs and (d) $Cs_2AgBiCl_6/PMMA$ CFs. (e) EDS spectrum of $Cs_2NaBiCl_6/PMMA$ CFs. The insets in (c) and (d) show the size statistics for $Cs_2NaBiCl_6$ MCs and $Cs_2AgBiCl_6$ MCs in PMMA respectively. The inset in e shows the mapping of elements in the $Cs_2NaBiCl_6/PMMA$ CFs as well as the quant results.

method similar to that of lead halide perovskite, where broadband orange emission peaks were observed at 580 nm with PLQY up to 11.4%.²¹ It can be seen that although these preparation strategies have resulted in lead-free DPs with excellent optical properties, the inevitable introduction of concentrated HCl and high temperatures in the synthesis process have added to the risk and cost of preparation that does not facilitate further commercial development.

Herein, a strategy for the in situ growth of lead-free DP in polymeric materials to get DP/polymer composite films (CFs) was proposed, which adopted low-risk dimethyl sulfoxide (DMSO) as a precursor solvent to achieve the preparation of high-quality CFs by crystallization at 100 °C for 1 h. Lead-free Cs₂NaBiCl₆ was chosen as the DP base and highly transmittance poly methyl methacrylate (PMMA) as the polymer base, resulting in a lower PLQY of the synthesized Cs₂NaBiCl₆/PMMA CFs attributed to the indirect band gap structure of Cs₂NaBiCl₆.²² Subsequently, Cs₂Na_{0.8}Ag_{0.2}BiCl₆/ PMMA CFs with a PLQY of up to 21.52% was further obtained by Ag⁺ doping, and monitoring the entire growth process revealed that it mainly consisted of the polymerization of the polymer as well as the crystallization of the DP, which laid the foundation for follow-up exploration. Additionally, this in situ fabrication strategy can be extended to other DP-based polymer CFs, showing some universality. Crucially, these CFs can be industrially prepared on a large scale, which holds great promise in the field of optoelectronic devices and anticounterfeit printing, promoting the development of lead-free DP materials in the commercial field.

RESULTS AND DISCUSSION

The $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs with different Ag^+ content was fabricated using a low-cost and low-risk in situ fabrication strategy. In a typical fabrication process, the raw materials of lead-free DP $Cs_2Na_{1-x}Ag_xBiCl_6$ and PMMA were first dissolved in a mild DMSO solvent to form the precursor solution. The choice of DMSO significantly alleviates the risks of preparation and the threat to the environment compared to conventional processes using concentrated HCl as a solvent. The precursor solution was then uniformly coated onto the substrate using a blade coater. Subsequently, the precursor-coated substrate was gradually heated to 100 °C to promote the formation of DP $Cs_2Na_{1-x}Ag_xBiCl_6$. Finally, the orange-emitting $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs were formed after holding for 1 h (Specific steps in Experimental Section).

The structure and microscopic morphology of Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs with different Ag⁺ content was further studied by X-ray diffraction (XRD), scanning electron microscope (SEM), and energy-dispersive spectroscopy (EDS) analysis. The XRD patterns of Cs₂Na_{1-x}Ag_xBiCl₆/ PMMA CFs with different Ag⁺ content showed that all samples crystallized in a DP crystal structure and the diffraction peaks were located between bulk Cs₂NaBiCl₆ (ICSD: 2738) and bulk Cs₂AgBiCl₆ (ICSD: 291598), with no secondary phases observed (Figure 1a). Further observations reveal that the intensity of the (111) plane diffraction peak (2θ angle of 14.14°) of bulk Cs₂NaBiCl₆ decreases when the Ag⁺ content in the Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs increases, which is related to the different scattering factor of the Na and Ag atoms.²³ After the doping content of Ag⁺ exceeds 60%, the main phase of the Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs will be presented as a bulk $Cs_2AgBiCl_6$ crystal structure, at which point the (111) plane diffraction peak of bulk Cs₂NaBiCl₆ was also no longer observable. Meanwhile, the magnification of XRD in the 22° -25° range indicated that the diffraction peaks were shifted to a higher 2θ angle as the Ag⁺ content increased in the Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs (Figure S1), which can be attributed to the lattice contraction caused by the substitution of Na⁺ by smaller Ag⁺.^{24,25} These results indicate the formation of alloyed DP crystals when working with an intermediate Na/ Ag composition. Interestingly, a broader diffraction peak located at 15° was found in the XRD patterns of all CFs, which corresponds exactly to the amorphous PMMA (Figure S2a), implying that the in situ fabrication strategy achieved the growth of Cs₂Na_{1-x}Ag_xBiCl₆ inside PMMA. Subsequently, the microscopic morphology of the pure PMMA film obtained by



Figure 2. (a) Absorbance (left) and normalized PL (right) spectra of $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs as the Ag^+ content increases (from the bottom curve corresponding to x = 0%, to the top curve corresponding to x = 100%). (b) Time-resolved PL spectra and fitted curves for CFs with different Ag^+ content. (c) The average lifetime τ_{ave} of CFS (hollow circles) and its corresponding PLQYS value (solid circles). (d) Photographs corresponding to $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs with different Ag^+ content under a 365 nm UV light.

the same fabrication strategy was observed (Figure 1b), and the corresponding SEM image revealing no other crystal material inside and clear colloidal streaks belonging to the conductive adhesive used below, a phenomenon that stems from the high transmittance (97%) of the pure PMMA film (Figure S2d). In contrast, Cs₂NaBiCl₆ microcrystals (MCs) and Cs₂AgBiCl₆ MCs with an average particle size of approximately $4-5 \ \mu m$ (insets of Figure 1c, d) appear in the Cs₂NaBiCl₆/PMMA CFs and Cs₂AgBiCl₆/PMMA CFs (Figure 1c, d), respectively, further demonstrating that DP have crystallized within the PMMA, completing the in situ composite of inorganic and organic materials. In addition, information on the chemical structure of Cs₂NaBiCl₆ solidstate alloy in PMMA was acquired by Raman spectroscopy. In Figure S3a, the Raman spectra of the pure PMMA film and Cs₂NaBiCl₆/PMMA CFs are provided, with both films displaying the strong vibrational peaks of PMMA. Exceptionally, two additional distinct vibrational modes are clearly visible in $Cs_2NaBiCl_6/PMMA$ CFs in the 50–500 cm⁻¹ range (Figure S3b) and these can be identified as F_{2g} (at 115.7 cm⁻¹) and A_{1g} (at 284.1 cm⁻¹). This pair of strong vibrational modes has been widely reported in pure phase Cs2NaBiCl6 DP and attributed to the internal vibrations of the $(BiCl_6)^{3-1}$ octahedron.²⁶⁻²⁸ Subsequently, EDS analysis results for Cs₂NaBiCl₆/PMMA CFs (Figure 1e) and Cs₂AgBiCl₆/ PMMA CFs (Figure S4a-i) further support the in situ formation of DP MCs, with the largest amounts of C and O elements from PMMA and elemental mapping reflecting the homogeneous distribution of $Cs_2NaBiCl_6$ (insets of Figure 1e) and Cs₂AgBiCl₆ (Figure S4b-i) in PMMA. At the same time, DP MCs with an average size of $4-5 \ \mu m$ were also found in $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs with different Ag^+ content

(Figure S5a-i), which confirms that this low-cost and low-risk in situ fabrication strategy can ensure uniform growth of DP MCs in PMMA by adjusting the precursor concentration and film formation temperature. Typically, trace amounts of Ag element were also detected in the EDS analysis result (Figure S6a-i) of the Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs with 20% Ag⁺ doping, which again reaffirms the successful fabrication of Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs with different Ag⁺ content. The transmittance of the Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs was also substantially reduced (Figure S7a-k), with only about 50% retained. Afterward, the thicknesses of the pure PMMA film and Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs were measured separately, and benefited from being prepared under the same conditions, both remaining at 50 μ m (Figure S8), thereby excluding the decay in transmittance caused by the uneven thickness of the polymer. Therefore, the reduced transmittance of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs stemmed mainly from the large number of Cs₂Na_{0.8}Ag_{0.2}BiCl₆ particles distributed in the PMMA film, which not only absorbed part of the visible light, but also the large particles prevented the transmission of visible light. These characterization results show that this strategy of using DMSO as a solvent for the in situ fabrication of Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs can achieve high quality crystallization of Cs₂Na_{1-x}Ag_xBiCl₆ in PMMA, with significant saving in cost and reduced experimental risk.

In order to better broaden the prospects of lead-free DP CFs for optoelectronic applications, the optical properties of $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs have been closely investigated. The UV–vis absorbance spectrum of $Cs_2NaBiCl_6/PMMA$ CFs indicated an absorption onset close to 350 nm and a strong exciton absorption peak at 310 nm (Figure 2a), where the pure PMMA film has no absorbance (Figure S2c); therefore it can



Figure 3. (a) Schematic illustration of the in situ fabrication of $Cs_2Na_{1-x}Ag_xBiCl_6$ embedded PMMA CFs. (b) Analytical diagram of the growth process of $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs under different classification criteria. (c) Photographs of the corresponding $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PMMA$ CFs under daylight and 365 nm UV light during the heat preservation process (Process II).

be attributed to the $6s^2 \rightarrow 6S \ 2p^1$ transitions of Bi^{3+.29} Meanwhile, the PL spectrum exhibits the fluorescence emission peak of Cs₂NaBiCl₆/PMMA CFs at 430 nm (Figure 2a), which corresponds exactly to the emission peak of the pure PMMA film (Figure S2b), a phenomenon attributed to the indirect band gap transition of Cs₂NaBiCl₆, displaying a remarkably low PLQY that results in the fluorescence being masked by PMMA.^{30,31} Therefore, it is essential to modify and extend the electronic and optical properties of Cs2NaBiCl6/ PMMA CFs for its application. According to previous reports, the Cl-p orbital mainly constitutes the valence band maximum (VBM) of Cs₂NaBiCl₆, and its conduction band minimum (CBM) comprises mainly Na-s and Bi-p orbitals.³² However, the energy band composition of Cs₂AgBiCl₆ was more complex, with its VBM being composed mainly of Ag-d, Bi-s, and Cl-p orbitals, and its Ag-s, Bi-p, and Cl-p orbitals making up the CBM.³³ Subsequently, doping with different content of Ag⁺ allows the Ag-d and Ag-s orbitals to participate in the formation of the VBM and CBM of Cs2NaBiCl6, thereby contributing to the modification of its electronic structure, which exhibits bright orange-emitting under 365 nm UV light (Figure 2d).³⁴ As the Ag^+ doping content increased from 0% to 100%, the exciton absorption peak of Cs₂Na_{1-x}Ag_xBiCl₆/ PMMA CFs was also red-shifted from 310 to 336 nm (Figure 2a and S9a) and a similar phenomenon was observed in its corresponding PL excitation (PLE) spectrum (Figure S10a-j), where the excitation peak was broader in the Ag⁺-doped (0% < 10%x < 100%) CFs than in the pure DP (Cs₂NaBiCl₆ and $Cs_2AgBiCl_6$) CFs, indicating a gradual transition from Cs2NaBiCl6/PMMA CFs to Cs2AgBiCl6/PMMA CFs. However, the position of the main PL emission peak stayed almost the same (at about 690 nm) despite the varying band gap energy of Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs with Ag⁺ doping (Figures 2a and S9a), which in combination with the red-shift phenomenon of the absorption peak caused a gradual decrease of the Stokes shift (Δ_{SS}) from 376 nm at x = 10% to 347 nm at x = 100% (Figure S9b). The above optical properties are mainly attributed to the fact that the emission peak of Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs originates from the self-

trapped exciton (STE) state PL emission, independent of the energy band edge state. Therefore, the addition of Ag⁺ only changed the energy band structure of Cs₂NaBiCl₆ without any significant effect on the PL peak position, and its energy band changed as shown in Figure S11. With increasing Ag⁺ content, the highest PLQY (21.52%) was achieved at x = 20% for $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs (Figure 2c), which was attributed to the introduction of extra [AgCl₆]⁵⁻ octahedrons in $Cs_2NaBiCl_6$ that would separate the original $[NaCl_6]^{5-1}$ octahedrons, further modifying the electronic structure of $Cs_2NaBiCl_6$. The introduction of the $[AgCl_6]^{5-}$ octahedrons severely hindered the spatial distribution of the STE state, leading to more holes and electrons being anchored around the adjacent $[NaCl_6]^{5-}$ and $[BiCl_6]^{3-}$ octahedrons, which effectively enhanced the overlap between electron and hole orbitals, making the formation of excitons much easier. On the other hand, the separation of [NaCl₆]⁵⁻ octahedrons by Ag⁺ doping was able to weaken the electron-phonon coupling effect in Cs₂NaBiCl₆, thereby effectively enhancing the PLQYs.^{35,36} In addition, the interaction between the functional groups such as -C=O in PMMA and undercoordinated Ag on the Cs₂Na_{1-x}Ag_xBiCl₆ surface can effectively passivate the surface defects by donating extranuclear electrons to the Ag atom,^{37,38} which also facilitates the enhancement of PLQYs. As the Ag doping continuously improves, the PLQY drops to 2.27% at x = 100%, at which point the Bi 5c ion in the Ag-rich system are surrounded by AgCl₆ octahedra, exhibiting mainly indirect bandgap properties that hinder its STE emission process.²⁵ Subsequent time-resolved PL measurements showed that the PL decays of all samples were perfectly fitted by a triexponential function (Figure 2b, Table S2), where the shortlived component (τ_1) of the PL decay can be assigned to nonradiative recombination, the middle-lived component (τ_2) assigned to radiative recombination and the long-lived component (τ_3) assigned to emission from the sub-bandgap state.¹² The results of the fitting (Table S2) showed that the radiative recombination rate (A2) of Cs2Na1-xAgxBiCl6/ PMMA CFs first raised and then dropped as the Ag⁺ content increased, which was consistent with the trend of its PLQYs,

suggesting that the primary role of Na⁺ was to inhibit nonradiative decay pathways competing with the radiative recombination of STE on a similar time scale.^{25,39} At x = 20%, the radiative recombination rate of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs reached a maximum of 22.14%, accompanied by its PLQYs at a maximum of 21.52%. In summary, the optical properties of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs obtained by in situ preparation are the most outstanding and offer great opportunities for development.

The crystallization process of Cs₂Na_{1-x}Ag_xBiCl₆ in PMMA was further analyzed in order to get a more comprehensive insight into the changes in the optical behaviors of Cs₂Na_{1-r}Ag₂BiCl₆/PMMA CFs during the preparation process. It can be seen from the schematic illustration that the in situ fabrication of Cs2Na1-xAgxBiCl6/PMMA CFs using a blade coater was easy (Figure 3a), enabling the crystalline growth of Cs₂Na_{1-x}Ag_xBiCl₆ in PMMA by one step, and the whole fabrication process was carried out under open-air environments (25 °C, 30% relative humidity (RH)), greatly reducing production costs, and facilitating large-scale industrial production. The preparation of Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs consists of three main processes (Figure 3b): Process I (heating), which mainly brings the precursor solution to a suitable temperature (100 °C), thereby ensuring that Cs₂Na_{1-x}Ag_xBiCl₆ can crystallized at this temperature; Process II (heat preservation), which focuses on achieving a perfect crystallization process of Cs₂Na_{1-x}Ag_xBiCl₆ in PMMA; and Process III (cooling), which collects the prepared Cs₂Na_{1-r}Ag_rBiCl₆/PMMA CFs. The crystallization of Cs₂Na_{1-r}Ag₂BiCl₆ in PMMA mainly occurred in process II, so Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs with the highest PLQY was the selected research subject for a more detailed in situ recording of its optical changes (Figure 3c). It can be seen that during the initial 20 min of heat preservation (100 °C), the CFs do not exhibit fluorescent properties and reflect blueviolet emission under 365 nm UV light, indicating that the Cs₂Na_{0.8}Ag_{0.2}BiCl₆ has not yet crystallized at this time, but only PMMA was being polymerized into film. The CFs exhibited weak fluorescence emission at 30 min of heat preservation, and CFs were collected under this condition for further characterization in order to gain insight into the crystallization of Cs₂Na_{0.8}Ag_{0.2}BiCl₆ at this time. The results indicate that the lower crystallinity of Cs₂Na_{0.8}Ag_{0.2}BiCl₆ in Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs obtained by heat preservation for 30 min (Figure S12a) caused the CFs to have a poor PL intensity (Figure S12b) and therefore did not present a significant orange emission under 365 nm UV light (Figure 3c). The excitation (Figure S12b) and absorption (Figure S12c) peaks of the CFs are in the same position as those mentioned previously and the transmittance (Figure S12d) of the CFs was reduced to 50% accompanying the progressive crystallization of Cs₂Na_{0.8}Ag_{0.2}BiCl₆ in PMMA. After that, the orange emission of Cs2Na0.8Ag02BiCl6/PMMA CFs also becomes more pronounced with the extended heat preservation time, implying that Cs₂Na_{0.8}Ag_{0.2}BiCl₆ has completely crystallized in PMMA by this time. In conclusion, the in situ crystallization of Cs₂Na_{1-x}Ag_xBiCl₆ in PMMA can be divided into two stages: Stage I: Before heat preservation for 30 min belongs to the PMMA polymerization stage, where PMMA prefers to polymerize into a film; Stage II: After 30 min of heat preservation belongs to the nucleation and growth stage of $Cs_2Na_{1-x}Ag_xBiCl_6$ inside the PMMA film (Figure 3b). Therefore, the technical key to the in situ preparation of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs was the controlled polymerization of PMMA and the crystallization of Cs₂Na_{1-x}Ag_xBiCl₆. Finally, atomic force microscopy (AFM) 3D images illustrate the surface morphology of the different films prepared using a blade coater in the $5 \times 5 \,\mu m^2$ area (Figure S13). It can be seen that the surface of the pure PMMA film was uniform, flat and smooth with surface roughness R_q and R_a of 0.342 and 0.272 nm, respectively (Figure S13a), which belong to a remarkably small surface roughness value. Compared to the pure PMMA film, the surface roughness of the in situ fabricated $Cs_2Na_{1-x}Ag_xBiCl_6$ was elevated to around 5 nm (R_q) and 3 nm (R_a) (Figure S13b-d). As a result, the change in the surface morphology of the CFs once again confirms the successful growth of Cs₂Na_{1-x}Ag_xBiCl₆ within PMMA, making the surface smoothness fall.

Subsequently, the impact of different heating rates and openair environments on the in situ fabrication process of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs was explored separately. In order to improve the productivity of CFs, the heating rates in Process I were increased to 5 °C/min and 10 °C/min, respectively. Unfortunately, the too fast heating rate resulted in nonuniform thermal shrinkage of the PMMA polymer, with $Cs_2Na_{0.8}Ag_{0.2}BiCl_6$ enrichment in some regions of CFs (Figure S14a-b), while a slower heating rate $(1 \, ^{\circ}C/min)$ can overcome this phenomenon allowing Cs2Na0.8Ag0.2BiCl6 to be grown uniformly in the PMMA. Additionally, the fabrication of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs under high temperature and humidity open-air environments (40 °C, 85% RH; and 40 °C, 90% RH) was simulated, thereby evaluating the universal suitability of the method. The results suggested that the morphology of CFs was not affected by the open-air environments (Figure S15a-b), and their optical properties did not show any weakening, with PLQYs of 21.36% and 20.91% respectively (insets of Figure S15a-b), which are generally consistent with the 21.52% obtained previously. This in situ fabrication strategy can be adapted to extreme open-air environments, attributed to the fact that the precursor solution will be kept at 100 °C for 1 h in Process II, where water will be removed from the DMSO, so that the environmental humidity will have little effect on its preparation. Moreover, the crystallization temperature of CFs was up to 100 °C, so that the room temperature was increased to 40 °C with no significant effect on the preparation process of Cs2Na0.8Ag0.2BiCl6/PMMA CFs. Especially, the stability of the luminescent material was important for its application in the optical field, so the stability of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs with the most outstanding optical properties was tested under different environments. Benefiting from the protection of the surface hydrophobic PMMA polymer layer, the Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs exhibited excellent optical stability in water solution, with its PL intensity remaining essentially unchanged after being immersed in water for 10 h (Figure S16a), and still holding a bright orange emission (inset of Figure S16a). Subsequently, the change in PL intensity of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs as storage time prolonged at different temperatures was explored, and the results showed that the decay trend of its PL intensity became significant with temperature increased (Figure S16b). Furthermore, the instantaneous PL spectra of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs at different temperatures were collected, and it can be seen that the PL intensity decreased with increasing temperature (Figure S17a). The PL intensity of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs was increased when the temperature returned to room



Figure 4. (a) EL spectrum and (b) CIE color coordinate of the NIR LED assembled for $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PMMA$ CFs. Changes in the (c) EL spectra, (d) CRI (blue point), and CCT (red point) of NIR LED at different drive currents. Changes in the (e) EL spectra, (f) CRI (blue point) and CCT (red point) of NIR LED driven by 100 mA current with extended operating time (24 h). The inset in (b) is photographs of the corresponding NIR LED in operation. The insets in (f) are photographs of the corresponding NIR LED before and after 24 h of operation, respectively.

temperature; however it was unable to recover to the initial PL intensity (Figure S17b). A similar phenomenon has been reported in lead halide perovskite,⁴⁰ which derived from the appearance of different trap states within Cs2Na0.8Ag0.2BiCl6 after heating, where recoverable PL belonging to temporary defect states and irrecoverable PL from permanent defect states. At the same time, the PL intensity loss ratio of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs was calculated to be 31% (Figure S17c), which was lower than that of the lead halide perovskite/polymer CFs,⁴¹ indicating that the lead-free perovskite structure was more stable than the lead halide perovskite. Correspondingly, the PL peak position of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs showed a blue shift when the temperature increased to 363 K (Figure S17d), which was due to the out-of-phase band-edge states stabilized as lattice dilation at the Brillouin zone boundary.⁴² The above stability tests indicated that the excellent water stability of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs allowed it to be suitable for optoelectronic devices under high humidity environments, setting the stage for its subsequent commercial development.

Remarkably, this strategy for the in situ fabrication of DP/ polymer CFs was versatile and can be extended to other DPbased polymer CFs. Through screening of the polymers, polyvinylidene difluoride (PVDF) was selected as the polymer phase benefiting from its ability to be well soluble in DMSO. Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PVDF CFs was obtained employing the same preparation method as before, with SEM image showing that $Cs_2Na_{0.8}Ag_{0.2}BiCl_6$ with an average particle size of approximately 5 μ m were also observed in PVDF (Figure S18a), which are consistent with the previous results in Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs, further suggesting that the crystallization of Cs2Na1-xAgxBiCl6 was independent of the choice of polymer. EDS analysis demonstrated that besides the constituent elements of Cs₂Na_{0.8}Ag_{0.2}BiCl₆, strong signals of elements C and F were detected, which derived from PVDF (Figure S18b-j). Subsequently, further characterization results revealed that the crystallinity of Cs2Na0.8Ag0.2BiCl6 in the Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PVDF CFs in situ fabricated at 100 °C remained high (Figure S19a), and that it also emitted bright orange light at 690 nm (Figure S19b), corresponding to a

PLQY value of 18.41%. Furthermore, the PLE (Figure S19b), absorbance (Figure S19c) and transmittance (Figure S19d) spectra of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PVDF CFs obtained by the same method are in general agreement with those of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs reported previously. The distinction was that the surface roughness R_q and R_a of the pure PVDF film reached 5.19 and 3.08 nm respectively (Figure S20a), which was not sufficiently smooth compared to the pure PMMA film. Eventually, the surface roughness of Cs2Na0.8Ag0.2BiCl6/PVDF CFs increases again to 9.38 nm (R_a) and 6.97 nm (R_a) when $Cs_2Na_{0.8}Ag_{0.2}BiCl_6$ has finished crystallizing in PVDF (Figure S20b). The above characterization results reinforce the universality of this in situ fabrication strategy for DP/polymer CFs and provide a solid basis for the future development of DPs. To facilitate overall comparison, Table S2 lists some other fabrication strategies for lead-free DP and their main optical parameters. Compared to other preparation strategies, the in situ fabrication of DP/ polymer CFs does not require the use of concentrated HCl, which greatly alleviates the risk of experimental and environmental pollution, and the reaction temperature and time are simultaneously lowered, allowing for effective cost savings in production. Moreover, the introduction of the blade coater has simplified the fabrication process and made it more suitable for large-scale production, which will enable DP/polymer CFs to play an indispensable role in the future of the optical field.

The PL spectra of $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs indicate an ultrawide emission covering the near-infrared (NIR) region, which renders them potentially promising for applications in NIR spectral detection and night vision. Subsequently, the $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PMMA$ CFs with the highest PLQY value was selected to be assembled with a commercial 365 nm UV LED chip to form a NIR LED and to further investigate its optoelectronic properties. As can be seen from the electroluminescence (EL) spectrum of the NIR LED (Figure 4a), its emission range extends from the visible region to the NIR region, in general agreement with the PL spectrum obtained as before, with the position of the emission peak center shifted to 680 nm, which stems from the inconsistent angle of the excitation source. The international commission on illumina-

www.acsami.org



Figure 5. Optical images of the large size (a, b) $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PMMA$ CFs and (c, d) $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PVDF$ CFs prepared in situ under daylight and 365 nm UV light, respectively. (e) Diagram of the anticounterfeiting print and the printed anticounterfeiting mark consisting of $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PMMA$ CFs.

tion (CIE) diagram for NIR LED displays the corresponding color coordinate as (0.48, 0.44) (Figure 4b), and the color area in which this coordinate positioned is consistent with the color of the device emission as observed by the naked eye, both appearing distinctly orange (inset of Figure 4b). The EL spectra of the NIR LED at different drive currents were recorded, no significant differences can be seen in the shape of the spectra and the position of the emission peaks, suggesting good current drive stability of the device (Figure 4c). In addition, no apparent saturation of the EL intensity was observed with increasing current, which indicates that the NIR LED assembled from Cs2Na0.8Ag0.2BiCl6/PMMA CFs are suitable for high-power lighting systems. At the same time, the color-rendering index (CRI) of NIR LED remains essentially at a relatively high value of 85 when the injection current ranges from 5 to 100 mA, and its correlated color temperature (CCT) display remains at approximately 2600 K, indicating a high emission purity at different drive currents (Figure 4d). Finally, the most significant evaluation criterion for the performance of optoelectronic devices was their long-term operating stability, so the changes in the EL spectra and intensity of NIR LED were monitored over a 24 h period at a high current of 100 mA. The results reveal that the EL spectra of NIR LED are almost unchanged and its main emission peak intensity at 680 nm matches the initial intensity, which is contributed to the extremely high optical stability of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs, unaffected by the UV chip (Figure 4e). Furthermore, the CRI of the device was also settled at 85 for different operating times, and its CCT display remained at 2600 K after 24 h of operation (Figure 4f). The combination of the above practical optoelectronic applications suggests that Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs have high optical stability and that the excellent operating performance exhibited by its assembly into NIR LED will provide a new option for the development of night vision tools.

Whether optical materials can be fabricated on a large scale will directly determine their future business promotion and application. Here, the preparation of large-size DP/polymer CFs was explored in depth to ensure that the strategy of in situ grown Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs and Cs₂Na_{1-x}Ag_xBiCl₆/ PVDF CFs has a high practical application value. Through scaling up the dosage of precursors in the same proportions, large sizes (14 \times 18 cm²) of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs and Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PVDF CFs were obtained, with other preparation conditions being unchanged (Figure 5a, c). As can be seen in the optical image under the 365 nm UV light, Cs₂Na_{0.8}Ag_{0.2}BiCl₆ was distributed very uniformly in PMMA and PVDF with a bright orange fluorescent emitted from both large-scale CFs (Figure 5b, d). On the other hand, Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs can be further applied to optical anticounterfeiting prints with the advantage that it is colorless and translucent in daylight (Figure 5a, c). The precursor solution of Cs2Na0.8Ag02BiCl6/PMMA CFs was processed into different patterns using inkjet printing technology, and then heated to complete the polymerization and crystallization for a high-quality anticounterfeiting mark, which displays an orange anticounterfeiting pattern under 365 nm UV light (Figure 5e). This versatile development of Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PMMA CFs and Cs₂Na_{0.8}Ag_{0.2}BiCl₆/ PVDF CFs will greatly improve their impact in the next generation of optical materials, furthermore allowing large scale in situ fabrication of DP/polymer CFs will also accelerate its commercialization.

CONCLUSION

In summary, we have proposed a convenient and lowconsumption synthetic strategy for the in situ fabrication of $Cs_2Na_{1-x}Ag_xBiCl_6$ /PMMA CFs using DMSO as a solvent at a lower temperature (100 °C), and analyzed in detail the complete crystallization process of $Cs_2Na_{1-x}Ag_xBiCl_6$ in PMMA. Compared to the traditional method of using concentrated hydrochloric acid as a solvent and slow crystallization at high temperatures, this method considerably lowers the cost and risk of preparation, preventing environmental pollution. Especially, the Cs2Na0.8Ag0.2BiCl6/PMMA CFs with 20% Ag⁺ doping exhibited enhanced PL performance under 365 nm UV light with an ultrawide emission wavelength covering the NIR region, corresponding to a PLQY of 21.52%. On this basis, the Cs₂Na_{0.8}Ag_{0.2}BiCl₆/PVDF CFs with the same emission wavelength was obtained by changing the composition of the polymer precursors, indicating the universality of this fabrication strategy. Moreover, the CFs were capable of large-scale industrial production, which paved the way for a subsequent commercialization process. More importantly, the CFs have an outstanding performance in the field of night vision as well as optical anticounterfeiting, so we believe this in situ synthesis strategy will dramatically facilitate the development of the lead-free DP, opening the door for future applications of DP/polymer CFs in flexible optics.

EXPERIMENTAL SECTION

Materials. The cesium chloride (CsCl, 99.99%), sodium chloride (NaCl, 99.5%), silver chloride (AgCl, 99.5%), bismuth chloride (BiCl₃, 99.99%), and dimethyl sulfoxide (DMSO, 99%) were purchased from Aladdin. The poly methyl methacrylate (PMMA) and poly(vinylidene fluoride) (PVDF) purchased from Macklin and Alfa Aesar, respectively. All the reagents were used without further purification.

Fabrication of Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs with Different Ag⁺ Content. The in situ fabrication of $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs consists of two main stages. Stage I: Preparation of the precursor solution and coating of the film. The precursor solution included 0.06 mmol CsCl, 0.03-X mmol NaCl (X = 0, 0.003, 0.006, 0.009, 0.012, 0.015, 0.018, 0.021, 0.024, 0.027, 0.03), X mmol AgCl and 0.03 mmol BiCl₃ in 10 mL of DMSO solvent with continuous stirring until complete dissolution. Subsequently, 1 g of PMMA particles was added to the mixed solution and stirred at 60 $^\circ$ C for 30 min until the PMMA particles were dissolved and finally cooled to room temperature. The above precursor solution was then applied uniformly to the substrate using a blade applicator to form a film. Stage II: The precursor coated substrate was gradually heated (1 °C/min) to 100 °C to promote the formation of DP Cs₂Na_{1-x}Ag_xBiCl₆. Afterward, the film was held at 100 °C for 1 h until the Cs₂Na_{1-x}Ag_xBiCl₆ was completely crystallized. Finally, Cs₂Na_{1-x}Ag_xBiCl₆/PMMA CFs was obtained by natural cooling to room temperature.

Fabrication of $Cs_2Na_{1-x}Ag_xBiCl_6/PVDF$ CFs with Different Ag⁺ Content. All steps are the same as for the fabrication of $Cs_2Na_{1-x}Ag_xBiCl_6/PMMA$ CFs, except that 1 g of PMMA particles are replaced by 1 g of PVDF powder, which can be dissolved at room temperature.

NIR LED Device Assembled by $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/PMMA$ CFs. To achieve a near-infrared emitting LED, $Cs_2Na_{0.8}Ag_{0.2}BiCl_6/$ PMMA CFs was cut to the right size and placed on the surface of a commercial UV LED chip (365 nm, EP-U4545K-A3, 3.7 V, 5W, Guanghong Technology, China) to be assembled into NIR LED device.

Characterization Methods. The morphology and EDS spectra of films were investigated by field emission scanning electron microscopy (SEM, FEI Quatan FEG 250) equipped with an energy dispersive spectrometer (EDS). The surface roughness of the films is obtained from atomic force microscopy (AFM, INNOVA). The photoluminescence (PL) spectra, PL quantum yields (PLQYs) and time-resolved PL (TRPL) decay curves were recorded on an Edinburgh Instruments FLS 1000 spectrometer. The ultraviolet– visible (UV–vis) absorption and transmittance spectra were recorded by PE Lambda 950. The X-ray diffraction (XRD) patterns were obtained using the DB-ADVANCE X-ray diffraction analyzer diffractometer. The PL spectra of the samples at different temperatures were collected by Photo Research 670 spectrometer after heating the samples using a heater (MS7–H550-S, DLAB, China) and under 365 nm UV light irradiation. The EL spectra of NIR LED were collected by a Keithley 2400 sourcemeter and a Photo Research 670 spectrometer. Raman experiments were performed on a HR Evolution-800 Raman microscope system (Horiba), equipped with standard 532 nm laser sources. High temperature and high humidity chambers (BDX-30F DONGGUAN BEIDOUXING TESTING EQUIPMENT CO. LTD) were adopted to provide constant humidity for the preparation of composite films in high humidity environments.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsami.2c22752.

XRD, SEM, and EDS data of CFs, Raman spectra, Transmittance spectra, PLE spectra, AFM topographies images of CFs, Energy band structure, water and thermal stability testing of CFs (Figures S1–S20), fitting results of PL decays, and comparison of our work and previous references (Tables S1 and S2) (PDF)

AUTHOR INFORMATION

Corresponding Author

Minqiang Wang – Electronic Materials Research Laboratory, Key Laboratory of the Ministry of Education International Center for Dielectric Research & Shannxi Engineering Research Center of Advanced Energy Materials and Devices, Xi'an Jiaotong University, 710049 Xi'an, China; Email: mgwang@xjtu.edu.cn

Authors

- Jindou Shi Electronic Materials Research Laboratory, Key Laboratory of the Ministry of Education International Center for Dielectric Research & Shannxi Engineering Research Center of Advanced Energy Materials and Devices, Xi'an Jiaotong University, 710049 Xi'an, China; Orcid.org/ 0000-0003-1082-5009
- Chen Zhang Electronic Materials Research Laboratory, Key Laboratory of the Ministry of Education International Center for Dielectric Research & Shannxi Engineering Research Center of Advanced Energy Materials and Devices, Xi'an Jiaotong University, 710049 Xi'an, China
- Junnan Wang Electronic Materials Research Laboratory, Key Laboratory of the Ministry of Education International Center for Dielectric Research & Shannxi Engineering Research Center of Advanced Energy Materials and Devices, Xi'an Jiaotong University, 710049 Xi'an, China;
 orcid.org/0000-0002-3074-0195
- Yun Zhou Electronic Materials Research Laboratory, Key Laboratory of the Ministry of Education International Center for Dielectric Research & Shannxi Engineering Research Center of Advanced Energy Materials and Devices, Xi'an Jiaotong University, 710049 Xi'an, China
- Youlong Xu Electronic Materials Research Laboratory, Key Laboratory of the Ministry of Education International Center for Dielectric Research & Shannxi Engineering Research Center of Advanced Energy Materials and Devices, Xi'an Jiaotong University, 710049 Xi'an, China
- Nikolai V. Gaponenko Belarusian State University of Informatics and Radioelectronics, 220013 Minsk, Belarus

Complete contact information is available at: https://pubs.acs.org/10.1021/acsami.2c22752

Notes

The authors declare no competing financial interest.

ACKNOWLEDGMENTS

This work was supported by the National Key R&D Program of China (2022YFE0122500 and 2019YFB1503200), National Natural Science Foundation of China (NSFC, 52161145103 and 61774124), and 111 Program (No. B14040), and Shaanxi Provincial Key Research and Development Program (No.2021GXLH-Z-084). The authors thank Ms. Dan He at Instrument Anaysis Center of Xi'an Jiaotong University for her the help with the time-resolved PL analysis.

REFERENCES

(1) Song, J. Z.; Li, J. H.; Li, X. M.; Xu, L. M.; Dong, Y. H.; Zeng, H. B. Quantum Dot Light-Emitting Diodes Based on Inorganic Perovskite Cesium Lead Halides (CsPbX₃). *Adv. Mater.* **2015**, *27*, 7162–7167.

(2) Wei, C. T.; Su, W. M.; Li, J. T.; Xu, B.; Shan, Q. S.; Wu, Y.; Zhang, F. J.; Luo, M. M.; Xiang, H. Y.; Cui, Z.; Zeng, H. B. A Universal Ternary-Solvent-Ink Strategy toward Efficient Inkjet-Printed Perovskite Quantum Dot Light-Emitting Diodes. *Adv. Mater.* **2022**, *34*, 2107798.

(3) Huang, X. J.; Guo, Q. Y.; Yang, D. D.; Xiao, X. D.; Liu, X. F.; Xia, Z. G.; Fan, F. J.; Qiu, J. R.; Dong, G. P. Reversible 3D Laser Printing of Perovskite Quantum Dots inside A Transparent Medium. *Nat. Photonics* **2020**, *14*, 82–88.

(4) Bohn, B. J.; Tong, Y.; Gramlich, M.; Lai, M. L.; Doblinger, M.; Wang, K.; Hoye, R. L. Z.; Muller-Buschbaum, P.; Stranks, S. D.; Urban, A. S.; Polavarapu, L.; Feldmann, J. Boosting Tunable Blue Luminescence of Halide Perovskite Nanoplatelets through Postsynthetic Surface Trap Repair. *Nano Lett.* **2018**, *18*, 5231–5238.

(5) Shamsi, J.; Urban, A. S.; Imran, M.; De Trizio, L.; Manna, L. Metal Halide Perovskite Nanocrystals: Synthesis, Post-Synthesis Modifications, and Their Optical Properties. *Chem. Rev.* **2019**, *119*, 3296–3348.

(6) Fu, H. Y. Review of Lead-Free Halide Perovskites as Light-Absorbers for Photovoltaic Applications: From Materials to Solar Cells. Sol Energ Mat Sol C 2019, 193, 107–132.

(7) Ghosh, S.; Pradhan, B. Lead-Free Metal Halide Perovskite Nanocrystals: Challenges, Applications, and Future Aspects. *Chemnanomat* **2019**, *5*, 300–312.

(8) Fan, Q. Q.; Biesold-McGee, G. V.; Ma, J. Z.; Xu, Q. N.; Pan, S.; Peng, J.; Lin, Z. Q. Lead-Free Halide Perovskite Nanocrystals: Crystal Structures, Synthesis, Stabilities, and Optical Properties. *Angew. Chem. Int. Edit* **2020**, *59*, 1030–1046.

(9) Jellicoe, T. C.; Richter, J. M.; Glass, H. F. J.; Tabachnyk, M.; Brady, R.; Dutton, S. E.; Rao, A.; Friend, R. H.; Credgington, D.; Greenham, N. C.; Bohm, M. L. Synthesis and Optical Properties of Lead-Free Cesium Tin Halide Perovskite Nanocrystals. *J. Am. Chem. Soc.* **2016**, *138*, 2941–2944.

(10) Wu, X. T.; Song, W. D.; Li, Q.; Zhao, X. X.; He, D. S.; Quan, Z.
W. Synthesis of Lead-Free CsGeI₃ Perovskite Colloidal Nanocrystals and Electron Beam-induced Transformations. *Chem-Asian J.* 2018, *13*, 1654–1659.

(11) Bekenstein, Y.; Dahl, J. C.; Huang, J. M.; Osowiecki, W. T.; Swabeck, J. K.; Chan, E. M.; Yang, P. D.; Alivisatos, A. P. The Making and Breaking of Lead-Free Double Perovskite Nanocrystals of Cesium Silver-Bismuth Halide Compositions. *Nano Lett.* **2018**, *18*, 3502– 3508. (12) Yang, B.; Chen, J. S.; Yang, S. Q.; Hong, F.; Sun, L.; Han, P. G.; Pullerits, T.; Deng, W. Q.; Han, K. L. Lead-Free Silver-Bismuth Halide Double Perovskite Nanocrystals. *Angew. Chem. Int. Edit* **2018**, *57*, 5359–5363.

(13) Yang, B.; Hong, F.; Chen, J. S.; Tang, Y. X.; Yang, L.; Sang, Y. B.; Xia, X. S.; Guo, J. W.; He, H. X.; Yang, S. Q.; Deng, W. Q.; Han, K. L. Colloidal Synthesis and Charge-Carrier Dynamics of $Cs_2AgSb_{1-y}Bi_yX_6$ (X: Br, Cl; $0 \le y \le 1$) Double Perovskite Nanocrystals. Angew. Chem. Int. Edit **2019**, 58, 2278–2283.

(14) Igbari, F.; Wang, Z. K.; Liao, L. S. Progress of Lead-Free Halide Double Perovskites. *Adv. Energy Mater.* **2019**, *9*, 1803150.

(15) Liu, Y.; Nag, A.; Manna, L.; Xia, Z. G. Lead-Free Double Perovskite $Cs_2AgInCl_6$. Angew. Chem. Int. Edit **2021**, 60, 11592–11603.

(16) Evans, C. D.; Monteith, D. T.; Fowler, D.; Cape, J. N.; Brayshaw, S. Hydrochloric Acid: An Overlooked Driver of Environmental Change. *Environ. Sci. Technol.* **2011**, *45*, 1887–1894.

(17) Li, S.; Shi, Z. F.; Zhang, F.; Wang, L. T.; Ma, Z. Z.; Wu, D.; Yang, D. W.; Chen, X.; Tian, Y. T.; Zhang, Y. T.; Shan, C. X.; Li, X. J. Ultrastable Lead-Free Double Perovskite Warm-White Light-Emitting Devices with A Lifetime above 1000 h. *ACS Appl. Mater. Inter* **2020**, *12*, 46330–46339.

(18) Yin, H.; Xian, Y. M.; Zhang, Y. L.; Chen, W. J.; Wen, X. M.; Rahman, N. U.; Long, Y.; Jia, B. H.; Fan, J. D.; Li, W. Z. An Emerging Lead-Free Double-Perovskite $Cs_2AgFeCl_6$:In Single Crystal. *Adv. Funct Mater.* **2020**, *30*, 2002225.

(19) Ahmad, R.; Zdrazil, L.; Kalytchuk, S.; Naldoni, A.; Rogach, A. L.; Schmuki, P.; Zboril, R.; Kment, S. Uncovering the Role of Trioctylphosphine on Colloidal and Emission Stability of Sb-Alloyed Cs₂NaInCl₆ Double Perovskite Nanocrystals. *ACS Appl. Mater. Inter* **2021**, *13*, 47845–47859.

(20) Zheng, W.; Li, X. L.; Liu, N. Q.; Yan, S.; Wang, X. J.; Zhang, X. Z.; Liu, Y. Q.; Liang, Y. J.; Zhang, Y. H.; Liu, H. Solution-Grown Chloride Perovskite Crystal of Red Afterglow. *Angew. Chem. Int. Edit* **2021**, *60*, 24450–24455.

(21) Liu, Y.; Jing, Y. Y.; Zhao, J.; Liu, Q. L.; Xia, Z. G. Design Optimization of Lead-Free Perovskite $Cs_2AgInCl_6$:Bi Nanocrystals with 11.4% Photoluminescence Quantum Yield. *Chem. Mater.* **2019**, *31*, 3333–3339.

(22) Morss, L. R.; Siegal, M.; Stenger, L.; Edelstein, N. Preparation of Cubic Chloro Complex Compounds of Trivalent Metals - Cs₂NaMCl₆. *Inorg. Chem.* **1970**, *9*, 1771–1775.

(23) Lim, T. W.; Kim, S. D.; Sung, K. D.; Rhyim, Y. M.; Jeen, H.; Yun, J.; Kim, K. H.; Song, K. M.; Lee, S.; Chung, S. Y.; Choi, M.; Choi, S. Y. Insights into Cationic Ordering in Re-Based Double Perovskite Oxides. *Sci. Rep* **2016**, *6*, 19746.

(24) Luo, J. J.; Wang, X. M.; Li, S. R.; Liu, J.; Guo, Y. M.; Niu, G. D.; Yao, L.; Fu, Y. H.; Gao, L.; Dong, Q. S.; Zhao, C. Y.; Leng, M. Y.; Ma, F. S.; Liang, W. X.; Wang, L. D.; Jin, S. Y.; Han, J. B.; Zhang, L. J.; Etheridge, J.; Wang, J. B.; Yan, Y. F.; Sargent, E. H.; Tang, J. Efficient and Stable Emission of Warm-White Light from Lead-Free Halide Double Perovskites. *Nature* **2018**, *563*, 541–545.

(25) Zhu, D. X.; Zito, J.; Pinchetti, V.; Dang, Z. Y.; Olivati, A.; Pasquale, L.; Tang, A. W.; Zaffalon, M. L.; Meinardi, F.; Infante, I.; De Trizio, L.; Manna, L.; Brovelli, S. Compositional Tuning of Carrier Dynamics in $Cs_2Na_{1-x}Ag_xBiCl_6$ Double-Perovskite Nanocrystals. ACS Energy Lett. **2020**, *5*, 1840–1847.

(26) Pelle, F.; Blanzat, B.; Chevalier, B. Low-Temperature Phase-Transition in Cubic Elpasolithe Crystal Cs₂NaBiCl₆. *Solid State Commun.* **1984**, *49*, 1089–1093.

(27) Smit, W. M. A.; Dirksen, G. J.; Stufkens, D. J. Infrared and Raman-Spectra of the Elpasolites $Cs_2NaSbCl_6$ and $Cs_2NaBiCl_6$ - Evidence for a Pseudo Jahn-Teller Distorted Ground-State. J. Phys. Chem. Solids **1990**, 51, 189–196.

(28) Dan, S.; Maiti, A.; Chatterjee, S.; Pal, A. J. Origin of Bandgap Bowing in $Cs_2Na_{1-x}Ag_xBiCl_6$ Double Perovskite Solid-State Alloys: A Paradigm through Scanning Tunneling Spectroscopy. *J. Phys-Condens Mat* **2021**, 33, 485701. (29) Majher, J. D.; Gray, M. B.; Strom, T. A.; Woodward, P. M. $Cs_2NaBiCl_6:Mn^{2+}$ - A New Orange-Red Halide Double Perovskite Phosphor. *Chem. Mater.* **2019**, *31*, 1738–1744.

(30) Shi, H. L.; Du, M. H. Discrete Electronic Bands in Semiconductors and Insulators: Potential High-Light-Yield Scintillators. *Phys. Rev. Appl.* **2015**, *3*, 054005.

(31) Hu, Q. S.; Niu, G. D.; Zheng, Z.; Li, S. R.; Zhang, Y. A.; Song, H. S.; Zhai, T. Y.; Tang, J. Tunable Color Temperatures and Efficient White Emission from $Cs_2Ag_{1-x}Na_xIn_{1-y}Bi_yCl_6$ Double Perovskite Nanocrystals. *Small* **2019**, *15*, 1903496.

(32) Zhou, J.; Rong, X. M.; Zhang, P.; Molokeev, M. S.; Wei, P. J.; Liu, Q. L.; Zhang, X. W.; Xia, Z. G. Manipulation of Bi^{3+}/In^{3+} Transmutation and Mn^{2+} -Doping Effect on the Structure and Optical Properties of Double Perovskite $Cs_2NaBi_{1-x}In_xCl_6$. *Adv. Opt Mater.* **2019**, 7, 1801435.

(33) Yang, B.; Mao, X.; Hong, F.; Meng, W. W.; Tang, Y. X.; Xia, X. S.; Yang, S. Q.; Deng, W. Q.; Han, K. L. Lead-Free Direct Band Gap Double-Perovskite Nanocrystals with Bright Dual-Color Emission. *J. Am. Chem. Soc.* **2018**, *140*, 17001–17006.

(34) Larnba, R. S.; Basera, P.; Bhattacharya, S.; Sapra, S. Band Gap Engineering in $Cs_2(Na_xAg_{1\cdot x})BiCl_6$ Double Perovskite Nanocrystals. *J. Phys. Chem. Lett.* **2019**, *10*, 5173–5181.

(35) Zhang, G. Y.; Wang, D. Y.; Lou, B. B.; Ma, C. G.; Meijerink, A.; Wang, Y. H. Efficient Broadband Near-Infrared Emission from Lead-Free Halide Double Perovskite Single Crystal. *Angew. Chem. Int. Edit* **2022**, *61*, e202207454.

(36) Pei, Y. F.; Tu, D. T.; Li, C. L.; Han, S. Y.; Xie, Z.; Wen, F.; Wang, L. P.; Chen, X. Y. Boosting Near-Infrared Luminescence of Lanthanide in $Cs_2AgBiCl_6$ Double Perovskites via Breakdown of the Local Site Symmetry. *Angew. Chem. Int. Edit* **2022**, *61*, e202205276.

(37) Li, J. B.; Yan, F. R.; Yang, P. Z.; Duan, Y. Y.; Duan, J. L.; Tang, Q. W. Suppressing Interfacial Shunt Loss via Functional Polymer for Performance Improvement of Lead-Free $Cs_2AgBiBr_6$ Double Perovskite Solar Cells. SOL RRL **2022**, *6*, 2100791.

(38) Aydin, E.; Bastiani, M.; Wolf, S. Defect and Contact Passivation for Perovskite Solar Cells. *Adv. Mater.* **2019**, *31*, 1900428.

(39) Locardi, F.; Sartori, E.; Buha, J.; Zito, J.; Prato, M.; Pinchetti, V.; Zaffalon, M. L.; Ferretti, M.; Brovelli, S.; Infante, I.; De Trizio, L.; Manna, L. Emissive Bi-Doped Double Perovskite Cs₂Ag_{1-x}NaxInCl₆ Nanocrystals. *ACS Energy Lett.* **2019**, *4*, 1976–1982.

(40) Shi, J. D.; Ge, W. Y.; Tian, Y.; Xu, M. M.; Gao, W. X.; Wu, Y. T. Enhanced Stability of All-Inorganic Perovskite Light-Emitting Diodes by A Facile Liquid Annealing Strategy. *Small* **2021**, *17*, 2006568.

(41) Shi, J. D.; Ge, W. Y.; Gao, W. X.; Xu, M. M.; Zhu, J. F.; Li, Y. X. Enhanced Thermal Stability of Halide Perovskite CsPbX₃ Nanocrystals by A Facile TPU Encapsulation. *Adv. Opt Mater.* **2020**, *8*, 1901516.

(42) Wright, A. D.; Verdi, C.; Milot, R. L.; Eperon, G. E.; Perez-Osorio, M. A.; Snaith, H. J.; Giustino, F.; Johnston, M. B.; Herz, L. M. Electron-Phonon Coupling in Hybrid Lead Halide Perovskites. *Nat. Commun.* 2016, 7, 11755.

Recommended by ACS

Bandlike Transport in FaPbBr₃ Quantum Dot Phototransistor with High Hole Mobility and Ultrahigh Photodetectivity

Rodrigo Ferreira, Santanu Jana, et al. NOVEMBER 11, 2022 NANO LETTERS

www.acsami.org

READ 🗹

READ Z

Crystallization and Defect Chemistry Dual Engineering for MAPbI₃ Perovskite Solar Cells with Efficiency Approaching 22%

Chen Wang, Shanpeng Wen, et al. DECEMBER 12, 2022 ACS SUSTAINABLE CHEMISTRY & ENGINEERING

3D/1D Architecture Using a 1-Hexyl-3-methylimidazolium Lead Triiodide Interlayer for Robust and Highly Performing Perovskite Solar Cells

Eleftherios Christopoulos, Polycarpos Falaras, *et al.* APRIL 14, 2023 ACS APPLIED ELECTRONIC MATERIALS

READ 🗹

Understanding the Working Mechanism of S^{2–} Ions on Compacted TiO₂ Layers in Cesium–Methylammonium–Formamidinium Perovskite S...

Bing Ou, Yiying Zhao, et al. NOVEMBER 14, 2022 ACS APPLIED ENERGY MATERIALS

READ 🗹

Get More Suggestions >